

4.0kV 1.0A HIGH VOLTAGE DIODE

HVRWx is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

■ Features

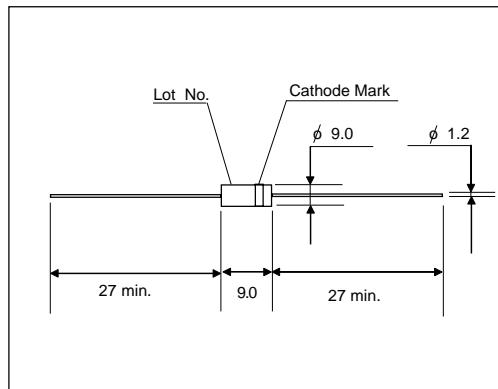
- High speed switching
- High Current
- High surge resistivity for CRT discharge
- High reliability design
- High Voltage

■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

■ Outline Drawings : mm**■ Cathode Mark**

Type	Mark
HVRW1	

Items	Symbols	Condition	HVRW4	Units
Repetitive Peak Reverse Voltage	V _{RRM}		4.0	kV
Average Output Current	I _o	T _a =25°C, Resistive Load	1.0	A _{peak}
Surge Current	I _{FSM}		50	A _{peak}
Junction Temperature	T _j		155	°C
Allowable Operation Case Temperature	T _c		125	°C
Storage Temperature	T _{stg}		-40 to +155	°C

- Electrical Characteristics (T_a=25°C Unless otherwise specified)

Items	Symbols	Conditions	HVRW4	Units
Maximum Forward Voltage Drop	V _F	at 25°C, I _F = I _{F(AV)}	6.0	V
Maximum Reverse Current	I _{R1}	at 25°C, V _R = V _{RRM}	50	uA
	I _{R2}	at 100°C, V _R = V _{RRM}	500	uA
Maximum Reverse Recovery Time	T _{rr}	at 25°C	150	nS
Junction Capacitance	C _j	at 25°C, V _R =0V, f=1MHz	--	pF